PDTC123T series

NPN resistor-equipped transistors; R1 = 2.2 k Ω , R2 = open Rev. 01 — 10 March 2006 Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistors (RET) family in Surface Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package	Package			
	Philips	JEITA	JEDEC		
PDTC123TE	SOT416	SC-75	-	PDTA123TE	
PDTC123TK	SOT346	SC-59A	TO-236	PDTA123TK	
PDTC123TM	SOT883	SC-101	-	PDTA123TM	
PDTC123TS[1]	SOT54	SC-43A	TO-92	PDTA123TS	
PDTC123TT	SOT23	-	TO-236AB	PDTA123TT	
PDTC123TU	SOT323	SC-70	-	PDTA123TU	

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Control of IC inputs

- Cost-saving alternative for BC847 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
I _O	output current		-	-	100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ



2. Pinning information

Table 3. **Pinning** Pin Description Simplified outline **Symbol** SOT54 1 input (base) output (collector) 3 GND (emitter) 001aab347 006aaa218 SOT54A 1 input (base) 2 output (collector) 3 GND (emitter) R1 001aab348 006aaa218 **SOT54** variant input (base) 2 output (collector) 3 GND (emitter) 001aab447 006aaa218 SOT23; SOT323; SOT346; SOT416 input (base) 3 2 GND (emitter) 3 output (collector) 2 006aaa144 sym012 **SOT883**



Transparent top view

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input (base)

GND (emitter)

output (collector)

1 2

3

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NPN resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

3. Ordering information

Table 4. Ordering information

Type number	Package	Package						
	Name	Description	Version					
PDTC123TE	SC-75	plastic surface mounted package; 3 leads	SOT416					
PDTC123TK	SC-59A	plastic surface mounted package; 3 leads	SOT346					
PDTC123TM	SC-101	leadless ultra small plastic package; 3 solder lands; body $1.0\times0.6\times0.5~\text{mm}$	SOT883					
PDTC123TS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54					
PDTC123TT	-	plastic surface mounted package; 3 leads	SOT23					
PDTC123TU	SC-70	plastic surface mounted package; 3 leads	SOT323					

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5. Marking codes

Tunio or Indiana.	
Type number	Marking code ^[1]
PDTC123TE	2B
PDTC123TK	GB
PDTC123TM	FB
PDTC123TS	TC123T
PDTC123TT	ZM*
PDTC123TU	*1T

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
Io	output current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	SOT416		<u>[1]</u> _	150	mW
	SOT346		<u>[1]</u> _	250	mW
	SOT883		[2][3]	250	mW
	SOT54		<u>[1]</u> -	500	mW
	SOT23		<u>[1]</u> -	250	mW
	SOT323		<u>[1]</u> -	200	mW
T _{stg}	storage temperature		–65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

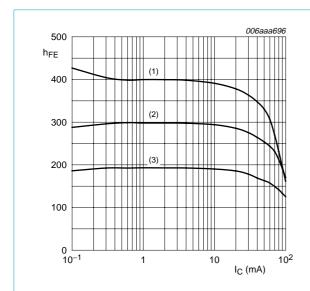
^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

7. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified.

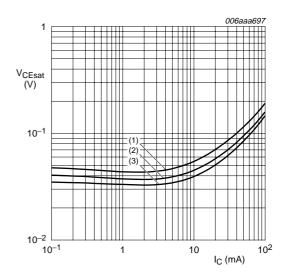
r arrib — 20	C directo carerwise openined.					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I_{CEO}	collector-emitter cut-off	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
cu	current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 20 \text{ mA}$	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	150	mV
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF





- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \,^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values

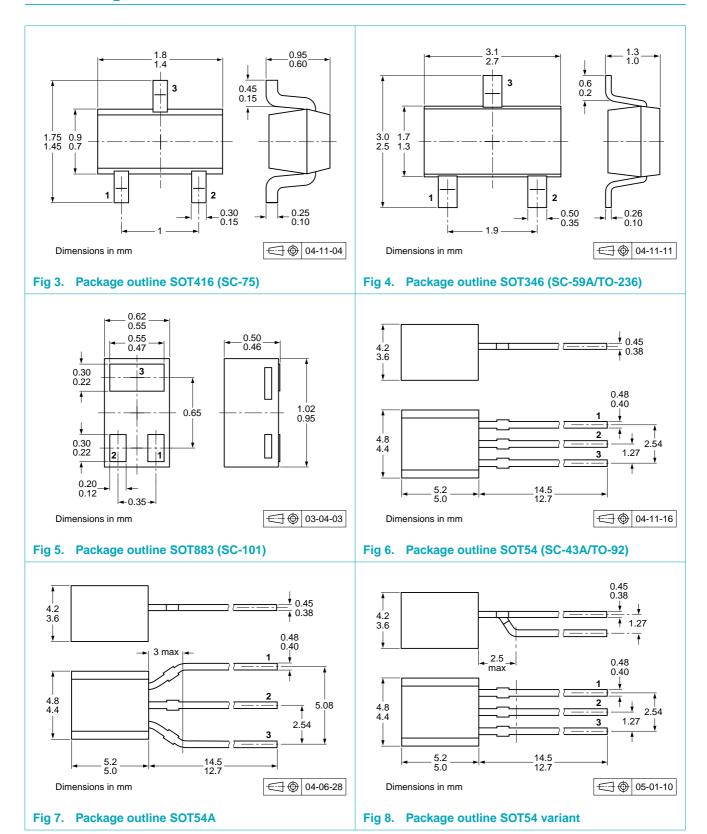


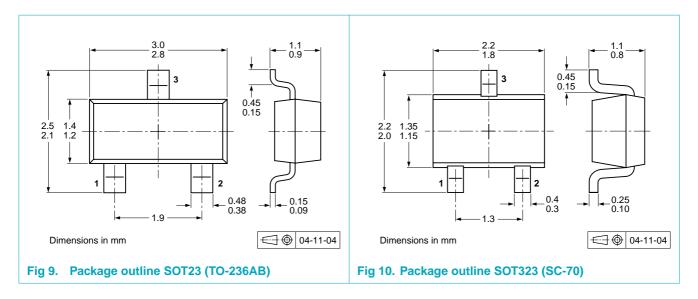
$$I_{\rm C}/I_{\rm B} = 20$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

8. Package outline





9. Packing information

Table 9. Packing methods
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Package	Description	Packing quantity			
		3000	5000	10000	
SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
SOT54	bulk, straight leads	-	-412	-	
SOT54A	tape and reel, wide pitch	-	-	-116	
	tape ammopack, wide pitch	-	-	-126	
SOT54 variant	bulk, delta pinning	-	-112	-	
SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	
	SOT416 SOT346 SOT883 SOT54 SOT54A SOT54 variant SOT23	SOT416 4 mm pitch, 8 mm tape and reel SOT346 4 mm pitch, 8 mm tape and reel SOT883 2 mm pitch, 8 mm tape and reel SOT54 bulk, straight leads SOT54A tape and reel, wide pitch tape ammopack, wide pitch SOT54 variant bulk, delta pinning SOT23 4 mm pitch, 8 mm tape and reel	3000 SOT416 4 mm pitch, 8 mm tape and reel -115 SOT346 4 mm pitch, 8 mm tape and reel -115 SOT883 2 mm pitch, 8 mm tape and reel - SOT54 bulk, straight leads - SOT54A tape and reel, wide pitch - tape ammopack, wide pitch - SOT54 variant bulk, delta pinning - SOT23 4 mm pitch, 8 mm tape and reel -215	3000 5000 SOT416 4 mm pitch, 8 mm tape and reel -115 - SOT346 4 mm pitch, 8 mm tape and reel -115 - SOT883 2 mm pitch, 8 mm tape and reel - - SOT54 bulk, straight leads - -412 SOT54A tape and reel, wide pitch - - tape ammopack, wide pitch - - SOT54 variant bulk, delta pinning - -112 SOT23 4 mm pitch, 8 mm tape and reel -215 -	

^[1] For further information and the availability of packing methods, see Section 12.

PDTC123T series

NPN resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC123T_SER_1	20060310	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PDTC123T series

NPN resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

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